NSN 5961-01-166-5929

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-166-5929 **Inclosure Material:** Glass **Overall Length:** 0.150 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1.2 forward voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 60.0 kilowatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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